





TL431, TL432 SLVS543R - AUGUST 2004 - REVISED OCTOBER 2023

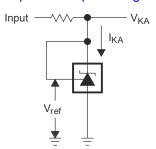
# TL431, TL432 Precision Programmable Reference

#### 1 Features

- Reference voltage tolerance at 25°C
  - 0.5% (B grade)
  - 1% (A grade)
  - 2% (Standard grade)
- Adjustable output voltage: V<sub>ref</sub> to 36 V
- Operation from -40°C to 125°C
- Typical temperature drift (TL43xB)
  - 6 mV (C temp)
  - 14 mV (I temp, Q temp)
- Low Output Noise
- $0.2-\Omega$  Typical output impedance
- Sink-current capability: 1 mA to 100 mA

## 2 Applications

- Rack server power
- Industrial AC/DC
- AC inverter & VF drives
- Servo drive control module
- Notebook PC power adapter design



**Simplified Schematic** 

## 3 Description

The TL431 and TL432 devices are three-terminal adjustable shunt regulators, with specified thermal stability over applicable automotive, commercial, and military temperature ranges. The output voltage can be set to any value between V<sub>ref</sub> (approximately 2.5 V) and 36 V, with two external resistors. These devices have a typical output impedance of 0.2 Ω. Active output circuitry provides a very sharp turn-on characteristic, making these devices excellent replacements for Zener diodes in many applications, such as on-board regulation, adjustable power supplies, and switching power supplies. The TL432 device has exactly the same functionality and electrical specifications as the TL431 device, but has different pinouts for the DBV, DBZ, and PK packages.

Both the TL431 and TL432 devices are offered in three grades, with initial tolerances (at 25°C) of 0.5%, 1%, and 2%, for the B, A, and standard grade, respectively. In addition, low output drift versus temperature ensures good stability over the entire temperature range.

The TL43xxC devices are characterized for operation from 0°C to 70°C, the TL43xxI devices are characterized for operation from -40°C to 85°C, and the TL43xxQ devices are characterized for operation from -40°C to 125°C.

#### **Device Information**

PART NUMBER (1)	PACKAGE (PIN)	BODY SIZE (NOM)
	SOT-23-3 (3)	2.90 mm × 1.30 mm
	SOT-23-5 (5)	2.90 mm × 1.60 mm
TL43x	SOIC (8)	4.90 mm × 3.90 mm
	PDIP (8)	9.50 mm × 6.35 mm
	SOP (8)	6.20 mm × 5.30 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Iable	OT	Contents	
1 Features		8.2 Dynamic Impedance	
2 Applications		9 Detailed Description	
3 Description		9.1 Overview	
4 Revision History		9.2 Functional Block Diagram	
5 Device Comparison Table		9.3 Feature Description	
6 Pin Configuration and Functions		9.4 Device Functional Modes	
7 Specifications		10 Applications and Implementation	
7.1 Absolute Maximum Ratings		10.1 Application Information	
7.2 ESD Ratings		10.2 Typical Applications	
7.3 Thermal Information		10.3 System Examples	
7.4 Recommended Operating Conditions		10.4 Power Supply Recommendations	31
7.5 Electrical Characteristics, TL431C, TL432C	6	10.5 Layout	31
7.6 Electrical Characteristics, TL431I, TL432I	7	11 Device and Documentation Support	32
7.7 Electrical Characteristics, TL431Q, TL432Q	8	11.1 Device Nomenclature	32
7.8 Electrical Characteristics, TL431AC, TL432AC	9	11.2 Related Links	
7.9 Electrical Characteristics, TL431AI, TL432AI	. 10	11.3 Receiving Notification of Documentation Upda	ates <mark>32</mark>
7.10 Electrical Characteristics, TL431AQ, TL432AQ	. 11	11.4 Support Resources	
7.11 Electrical Characteristics, TL431BC, TL432BC	. 12	11.5 Trademarks	32
7.12 Electrical Characteristics, TL431BI, TL432BI	. 13	11.6 Electrostatic Discharge Caution	
7.13 Electrical Characteristics, TL431BQ, TL432BQ	.14	11.7 Glossary	33
7.14 Typical Characteristics	. 15	12 Mechanical, Packaging, and Orderable	
8 Parameter Measurement Information	.19	Information	33
8.1 Temperature Coefficient	.19		
4 Revision History		(4	<b>D</b>
Changes from Revision Q (July 2022) to Revisio		· •	Page
•			
<ul> <li>Added detailed Temperature Coefficient and Dyn</li> </ul>	nami	c Impedance sections	19
Updated Applications section			<mark>26</mark>
Changes from Revision P (November 2018) to R	evisi	on Q (July 2022)	Page
<ul> <li>Updated the numbering format for tables, figures</li> </ul>	s. an	d cross-references throughout the document	1

Changes from Revision O (January 2015) to Revision P (November 2018)	Page

•	Added text to the Description section	
•	Added TL43x Device Comparison Table	3
	Added TL43x Device Nomenclature section	

## Changes from Revision N (January 2014) to Revision O (January 2015)

Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information	
table, Feature Description section, Device Functional Modes, Application and Implementation section, Power	
Supply Recommendations section, Layout section, Device and Documentation Support section, and	
Mechanical, Packaging, and Orderable Information section	

Mechanical, Packaging, and Orderable In Added Applications......1

**Page** 



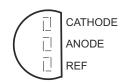
# **5 Device Comparison Table**

DEVICE PINOUT	INITIAL ACCURACY	OPERATING FREE-AIR TEMPERATURE (T <sub>A</sub> )				
TL431 TL432	B: 0.5% A: 1% (Blank): 2%	C: 0°C to 70°C I: -40°C to 85°C Q: -40°C to 125°C				

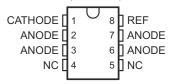


## 6 Pin Configuration and Functions

TL431, TL431A, TL431B . . . LP (TO-92/TO-226) PACKAGE (TOP VIEW)



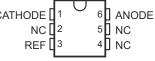
TL431, TL431A, TL431B . . . D (SOIC) PACKAGE (TOP VIEW)



NC - No internal connection

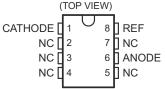
TL431A, TL431B ... DCK (SC-70) PACKAGE (TOP VIEW)

CATHODE 1 6 ANODE



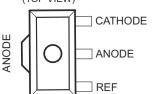
NC - No internal connection

TL431, TL431A, TL431B . . . P (PDIP), PS (SOP), OR PW (TSSOP) PACKAGE (TOP VIEW)

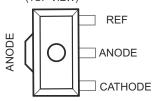


NC - No internal connection

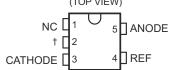
TL431, TL431A, TL431B . . . PK (SOT-89) PACKAGE (TOP VIEW)



TL432, TL432A, TL432B . . . PK (SOT-89) PACKAGE (TOP VIEW)



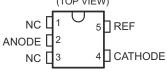
TL431, TL431A, TL431B . . . DBV (SOT-23-5) PACKAGE (TOP VIEW)



NC – No internal connection

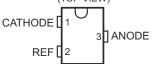
† Pin 2 is attached to Substrate and must be connected to ANODE or left open.

TL432, TL432A, TL432B . . . DBV (SOT-23-5) PACKAGE (TOP VIEW)

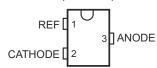


NC - No internal connection

TL431, TL431A, TL431B . . . DBZ (SOT-23-3) PACKAGE (TOP VIEW)



TL432, TL432A, TL432B . . . DBZ (SOT-23-3) PACKAGE (TOP VIEW)



**Table 6-1. Pin Functions** 

		PIN										
	TL431x							TL432x T			TYPE	DESCRIPTION
NAME	DBZ	DBV	PK	D	P, PS PW	LP	DCK	DBZ	DBV	PK		220.00
CATHODE	1	3	3	1	1	1	1	2	4	1	I/O	Shunt Current/Voltage input
REF	2	4	1	8	8	3	3	1	5	3	I	Threshold relative to common anode
ANODE	3	5	2	2, 3, 6, 7	6	2	6	3	2	2	0	Common pin, normally connected to ground

## 7 Specifications

## 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
V <sub>KA</sub>	Cathode Voltage <sup>(2)</sup>		37	V
I <sub>KA</sub>	Continuos Cathode Current Range	-100	150	mA
I <sub>I(ref)</sub>	Reference Input Current	-0.05	10	mA
TJ	Operating Junction Temperature Range		150	°C
T <sub>stg</sub>	Storage Temperature Range	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 7.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001pins <sup>(1)</sup>	±2000	\/
V <sub>(ESD)</sub>	discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	±1000	V

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions.

#### 7.3 Thermal Information

						TL43xx					
THERMAL METRIC(1)		Р	PW	D	PS	DCK	DBV	DBZ	LP	PK	UNIT
			8 PINS				5 PINS	PINS 3 PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance	85	149	97	95	259	206	206	140	52	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	57	65	39	46	87	131	76	55	9	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953)

## 7.4 Recommended Operating Conditions

See (1)

			MIN	MAX	UNIT
V <sub>KA</sub>	Cathode Voltage		V <sub>ref</sub>	36	V
I <sub>KA</sub>	Continuous Cathode Current Range		1	100	mA
		TL43xxC	0	70	
T <sub>A</sub>	Operating Free-Air Temperature	TL43xxI	-40	85	°C
		TL43xxQ	-40	125	

<sup>(1)</sup> Maximum power dissipation is a function of  $T_{J(max)}$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_{J(max)} - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.

<sup>(2)</sup> All voltage values are with respect to ANODE, unless otherwise noted.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.



# 7.5 Electrical Characteristics, TL431C, TL432C

over recommended operating conditions, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CIRCUIT	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
V <sub>ref</sub>	Reference Voltage	See Figure 8-1	$V_{KA} = V_{ref}$ , $I_{KA} = 10 \text{ mA}$		2440	2495	2550	mV
V <sub>I(dev)</sub>	Deviation of reference input voltage over full	See Figure 8-1	V <sub>KA</sub> = V <sub>ref</sub> , I <sub>KA</sub> = 10 mA	SOT23-3 and TL432 devices		6	16	mV
, ,	temperature range (1)			All other devices		4	25	mV
	Ratio of change in			$\Delta V_{KA} = 10 \text{ V} - V_{ref}$		-1.4	-2.7	mV/V
ΔV <sub>ref</sub> / ΔV <sub>KA</sub>	reference voltage to the change in cathode voltage	See Figure 8-2	I <sub>KA</sub> = 10 mA	ΔV <sub>KA</sub> = 36 V - 10 V		-1	-2	mV/V
I <sub>ref</sub>	Reference Input Current	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		2	4	μA
I <sub>I(dev)</sub>	Deviation of reference input current over full temperature range (1)	See Figure 8-2	I <sub>KA</sub> = 10 mA, R1 = 10kΩ,	R2 = ∞		0.4	1.2	μА
I <sub>min</sub>	Minimum cathode current for regulation	See Figure 8-1	$V_{KA} = V_{ref}$			0.4	1	mA
I <sub>off</sub>	Off-state cathode current	See Figure 8-3	V <sub>KA</sub> = 36 V, V <sub>ref</sub> = 0			0.1	1	μA
Z <sub>KA</sub>	Dynamic Impedance (2)	See Figure 8-1	$V_{KA} = V_{ref}, f \le 1 \text{ kHz},$ $I_{KA} = 1 \text{ mA to } 100 \text{ mA}$			0.2	0.5	Ω

The deviation parameters  $V_{I(dev)}$  and  $I_{I(dev)}$  are defined as the differences between the maximum and minimum values obtained over the rated temperature range. For more details on  $V_{I(dev)}$  and how it relates to the average temperature coefficient, see Temperature

Product Folder Links: TL431 TL432

The dynamic impedance is defined by  $|Z_{KA}| = \Delta V_{KA}/\Delta I_{KA}$ . For more details on  $|Z_{KA}|$  and how it relates to  $V_{KA}$ , see Dynamic (2)

## 7.6 Electrical Characteristics, TL431I, TL432I

over recommended operating conditions, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CIRCUIT	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
V <sub>ref</sub>	Reference Voltage	See Figure 8-1	$V_{KA} = V_{ref}$ , $I_{KA} = 10 \text{ mA}$		2440	2495	2550	mV
V <sub>I(dev)</sub>	Deviation of reference input voltage over full	See Figure 8-1	$V_{KA} = V_{ref}$ , $I_{KA} = 10 \text{ mA}$	SOT23-3 and TL432 devices		14	34	mV
. ,	temperature range (1)			All other devices		5	50	mV
	Ratio of change in			$\Delta V_{KA} = 10 \text{ V} - V_{ref}$		-1.4	-2.7	mV/V
ΔV <sub>ref</sub> / ΔV <sub>KA</sub>	reference voltage to the change in cathode voltage	See Figure 8-2	I <sub>KA</sub> = 10 mA	ΔV <sub>KA</sub> = 36 V - 10 V		-1	-2	mV/V
I <sub>ref</sub>	Reference Input Current	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		2	4	μΑ
I <sub>I(dev)</sub>	Deviation of reference input current over full temperature range (1)	See Figure 8-2	I <sub>KA</sub> = 10 mA, R1 = 10kΩ,	R2 = ∞		0.8	2.5	μА
I <sub>min</sub>	Minimum cathode current for regulation	See Figure 8-1	$V_{KA} = V_{ref}$			0.4	1	mA
I <sub>off</sub>	Off-state cathode current	See Figure 8-3	V <sub>KA</sub> = 36 V, V <sub>ref</sub> = 0			0.1	1	μΑ
Z <sub>KA</sub>	Dynamic Impedance (2)	See Figure 8-1	$V_{KA} = V_{ref}, f \le 1 \text{ kHz},$ $I_{KA} = 1 \text{ mA to } 100 \text{ mA}$			0.2	0.5	Ω

<sup>(1)</sup> The deviation parameters V<sub>I(dev)</sub> and I<sub>I(dev)</sub> are defined as the differences between the maximum and minimum values obtained over the rated temperature range. For more details on V<sub>I(dev)</sub> and how it relates to the average temperature coefficient, see Temperature Coefficient

<sup>(2)</sup> The dynamic impedance is defined by  $|Z_{KA}| = \Delta V_{KA}/\Delta I_{KA}$ . For more details on  $|Z_{KA}|$  and how it relates to  $V_{KA}$ , see Dynamic Impedance.



## 7.7 Electrical Characteristics, TL431Q, TL432Q

over recommended operating conditions, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CIRCUIT	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
V <sub>ref</sub>	Reference Voltage	See Figure 8-1	V <sub>KA</sub> = V <sub>ref</sub> , I <sub>KA</sub> = 10 mA		2440	2495	2550	mV
V <sub>I(dev)</sub>	Deviation of reference input voltage over full temperature range (1)	See Figure 8-1	V <sub>KA</sub> = V <sub>ref</sub> , I <sub>KA</sub> = 10 mA			14	34	mV
	Ratio of change in			$\Delta V_{KA} = 10 \text{ V} - V_{ref}$		-1.4	-2.7	mV/V
$\Delta V_{ref} / \Delta V_{KA}$	reference voltage to the change in cathode voltage	See Figure 8-2	I <sub>KA</sub> = 10 mA	ΔV <sub>KA</sub> = 36 V - 10 V		-1	-2	mV/V
I <sub>ref</sub>	Reference Input Current	See Figure 8-2	I <sub>KA</sub> = 10 mA, R1 = 10kΩ, R2 = ∞			2	4	μA
I <sub>I(dev)</sub>	Deviation of reference input current over full temperature range (1)	See Figure 8-2	I <sub>KA</sub> = 10 mA, R1 = 10kΩ,	R2 = ∞		0.8	2.5	μА
I <sub>min</sub>	Minimum cathode current for regulation	See Figure 8-1	$V_{KA} = V_{ref}$			0.4	1	mA
I <sub>off</sub>	Off-state cathode current	See Figure 8-3	V <sub>KA</sub> = 36 V, V <sub>ref</sub> = 0			0.1	1	μA
Z <sub>KA</sub>	Dynamic Impedance (2)	See Figure 8-1	$V_{KA} = V_{ref}, f \le 1 \text{ kHz},$ $I_{KA} = 1 \text{ mA to } 100 \text{ mA}$			0.2	0.5	Ω

The deviation parameters  $V_{I(dev)}$  and  $I_{I(dev)}$  are defined as the differences between the maximum and minimum values obtained over the rated temperature range. For more details on  $V_{I(dev)}$  and how it relates to the average temperature coefficient, see Temperature

Product Folder Links: TL431 TL432

<sup>(2)</sup> The dynamic impedance is defined by  $|Z_{KA}| = \Delta V_{KA}/\Delta I_{KA}$ . For more details on  $|Z_{KA}|$  and how it relates to  $V_{KA}$ , see Dynamic

## 7.8 Electrical Characteristics, TL431AC, TL432AC

over recommended operating conditions, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CIRCUIT	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
$V_{ref}$	Reference Voltage	See Figure 8-1	$V_{KA} = V_{ref}$ , $I_{KA} = 10 \text{ mA}$		2470	2495	2520	mV
V <sub>I(dev)</sub>	Deviation of reference input voltage over full	See Figure 8-1	V <sub>KA</sub> = V <sub>ref</sub> , I <sub>KA</sub> = 10 mA	SOT23-3 and TL432 devices		6	16	mV
, ,	temperature range (1)			All other devices		4	25	mV
	Ratio of change in			ΔV <sub>KA</sub> = 10 V - V <sub>ref</sub>		-1.4	-2.7	mV/V
$\Delta V_{ref} / \Delta V_{KA}$	reference voltage to the change in cathode voltage	See Figure 8-2	I <sub>KA</sub> = 10 mA	ΔV <sub>KA</sub> = 36 V - 10 V		-1	-2	mV/V
I <sub>ref</sub>	Reference Input Current	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		2	4	μA
I <sub>I(dev)</sub>	Deviation of reference input current over full temperature range (1)	See Figure 8-2	I <sub>KA</sub> = 10 mA, R1 = 10kΩ,	R2 = ∞		0.8	1.2	μА
I <sub>min</sub>	Minimum cathode current for regulation	See Figure 8-1	$V_{KA} = V_{ref}$			0.4	0.6	mA
I <sub>off</sub>	Off-state cathode current	See Figure 8-3	V <sub>KA</sub> = 36 V, V <sub>ref</sub> = 0			0.1	0.5	μA
Z <sub>KA</sub>	Dynamic Impedance (2)	See Figure 8-1	$V_{KA} = V_{ref}, f \le 1 \text{ kHz},$ $I_{KA} = 1 \text{ mA to } 100 \text{ mA}$			0.2	0.5	Ω

<sup>(1)</sup> The deviation parameters V<sub>I(dev)</sub> and I<sub>I(dev)</sub> are defined as the differences between the maximum and minimum values obtained over the rated temperature range. For more details on V<sub>I(dev)</sub> and how it relates to the average temperature coefficient, see Temperature Coefficient.

<sup>(2)</sup> The dynamic impedance is defined by  $|Z_{KA}| = \Delta V_{KA}/\Delta I_{KA}$ . For more details on  $|Z_{KA}|$  and how it relates to  $V_{KA}$ , see Dynamic Impedance.



## 7.9 Electrical Characteristics, TL431AI, TL432AI

over recommended operating conditions, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CIRCUIT	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
V <sub>ref</sub>	Reference Voltage	See Figure 8-1	$V_{KA} = V_{ref}$ , $I_{KA} = 10 \text{ mA}$		2470	2495	2520	mV
V <sub>I(dev)</sub>	Deviation of reference input voltage over full	See Figure 8-1	V <sub>KA</sub> = V <sub>ref</sub> , I <sub>KA</sub> = 10 mA	SOT23-3 and TL432 devices		14	34	mV
	temperature range (1)			All other devices		5	50	mV
	Ratio of change in			$\Delta V_{KA}$ = 10 V - $V_{ref}$		-1.4	-2.7	mV/V
$\Delta V_{ref} / \Delta V_{KA}$	reference voltage to the change in cathode voltage	See Figure 8-2	I <sub>KA</sub> = 10 mA	ΔV <sub>KA</sub> = 36 V - 10 V		-1	-2	mV/V
I <sub>ref</sub>	Reference Input Current	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		2	4	μΑ
I <sub>I(dev)</sub>	Deviation of reference input current over full temperature range (1)	See Figure 8-2	I <sub>KA</sub> = 10 mA, R1 = 10kΩ,	R2 = ∞		0.8	2.5	μА
I <sub>min</sub>	Minimum cathode current for regulation	See Figure 8-1	$V_{KA} = V_{ref}$			0.4	0.7	mA
I <sub>off</sub>	Off-state cathode current	See Figure 8-3	V <sub>KA</sub> = 36 V, V <sub>ref</sub> = 0			0.1	0.5	μA
Z <sub>KA</sub>	Dynamic Impedance (2)	See Figure 8-1	$V_{KA} = V_{ref}, f \le 1 \text{ kHz},$ $I_{KA} = 1 \text{ mA to } 100 \text{ mA}$			0.2	0.5	Ω

The deviation parameters  $V_{I(dev)}$  and  $I_{I(dev)}$  are defined as the differences between the maximum and minimum values obtained over the rated temperature range. For more details on  $V_{I(dev)}$  and how it relates to the average temperature coefficient, see Temperature

Product Folder Links: TL431 TL432

The dynamic impedance is defined by  $|Z_{KA}| = \Delta V_{KA}/\Delta I_{KA}$ . For more details on  $|Z_{KA}|$  and how it relates to  $V_{KA}$ , see Dynamic (2)



## 7.10 Electrical Characteristics, TL431AQ, TL432AQ

over recommended operating conditions, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CIRCUIT	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
V <sub>ref</sub>	Reference Voltage	See Figure 8-1	$V_{KA} = V_{ref}$ , $I_{KA} = 10 \text{ mA}$		2470	2495	2520	mV
V <sub>I(dev)</sub>	Deviation of reference input voltage over full temperature range (1)	See Figure 8-1	$V_{KA} = V_{ref}$ , $I_{KA} = 10 \text{ mA}$			14	34	mV
<b>A</b> \ /	Ratio of change in			$\Delta V_{KA} = 10 \text{ V} - V_{ref}$		-1.4	-2.7	mV/V
$\Delta V_{ref}$ / $\Delta V_{KA}$	reference voltage to the change in cathode voltage	See Figure 8-2	I <sub>KA</sub> = 10 mA	ΔV <sub>KA</sub> = 36 V - 10 V		<b>–</b> 1	-2	mV/V
I <sub>ref</sub>	Reference Input Current	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		2	4	μΑ
I <sub>I(dev)</sub>	Deviation of reference input current over full temperature range (1)	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		0.8	2.5	μА
I <sub>min</sub>	Minimum cathode current for regulation	See Figure 8-1	V <sub>KA</sub> = V <sub>ref</sub>			0.4	0.7	mA
I <sub>off</sub>	Off-state cathode current	See Figure 8-3	V <sub>KA</sub> = 36 V, V <sub>ref</sub> = 0			0.1	0.5	μΑ
Z <sub>KA</sub>	Dynamic Impedance (2)	See Figure 8-1	$V_{KA} = V_{ref}, f \le 1 \text{ kHz},$ $I_{KA} = 1 \text{ mA to } 100 \text{ mA}$			0.2	0.5	Ω

<sup>(1)</sup> The deviation parameters V<sub>I(dev)</sub> and I<sub>I(dev)</sub> are defined as the differences between the maximum and minimum values obtained over the rated temperature range. For more details on V<sub>I(dev)</sub> and how it relates to the average temperature coefficient, see Temperature Coefficient.

<sup>(2)</sup> The dynamic impedance is defined by  $|Z_{KA}| = \Delta V_{KA}/\Delta I_{KA}$ . For more details on  $|Z_{KA}|$  and how it relates to  $V_{KA}$ , see Dynamic Impedance.



## 7.11 Electrical Characteristics, TL431BC, TL432BC

over recommended operating conditions, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CIRCUIT	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
V <sub>ref</sub>	Reference Voltage	See Figure 8-1	$V_{KA} = V_{ref}$ , $I_{KA} = 10 \text{ mA}$		2483	2495	2507	mV
V <sub>I(dev)</sub>	Deviation of reference input voltage over full temperature range (1)	See Figure 8-1	$V_{KA} = V_{ref}$ , $I_{KA} = 10 \text{ mA}$			6	16	mV
	Ratio of change in			$\Delta V_{KA} = 10 \text{ V} - V_{ref}$		-1.4	-2.7	mV/V
$\Delta V_{ref} / \Delta V_{KA}$	reference voltage to the change in cathode voltage	See Figure 8-2	I <sub>KA</sub> = 10 mA	ΔV <sub>KA</sub> = 36 V - 10 V		-1	-2	mV/V
I <sub>ref</sub>	Reference Input Current	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		2	4	μA
I <sub>I(dev)</sub>	Deviation of reference input current over full temperature range (1)	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		0.8	1.2	μА
I <sub>min</sub>	Minimum cathode current for regulation	See Figure 8-1	$V_{KA} = V_{ref}$			0.4	0.6	mA
I <sub>off</sub>	Off-state cathode current	See Figure 8-3	V <sub>KA</sub> = 36 V, V <sub>ref</sub> = 0			0.1	0.5	μA
Z <sub>KA</sub>	Dynamic Impedance (2)	See Figure 8-1	$V_{KA} = V_{ref}, f \le 1 \text{ kHz},$ $I_{KA} = 1 \text{ mA to } 100 \text{ mA}$			0.2	0.5	Ω

The deviation parameters  $V_{I(dev)}$  and  $I_{I(dev)}$  are defined as the differences between the maximum and minimum values obtained over the rated temperature range. For more details on  $V_{I(dev)}$  and how it relates to the average temperature coefficient, see Temperature

Product Folder Links: TL431 TL432

<sup>(2)</sup> The dynamic impedance is defined by  $|Z_{KA}| = \Delta V_{KA}/\Delta I_{KA}$ . For more details on  $|Z_{KA}|$  and how it relates to  $V_{KA}$ , see Dynamic



## 7.12 Electrical Characteristics, TL431BI, TL432BI

over recommended operating conditions, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CIRCUIT	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
$V_{ref}$	Reference Voltage	See Figure 8-1	$V_{KA} = V_{ref}$ , $I_{KA} = 10 \text{ mA}$		2483	2495	2507	mV
V <sub>I(dev)</sub>	Deviation of reference input voltage over full temperature range (1)	See Figure 8-1	V <sub>KA</sub> = V <sub>ref</sub> , I <sub>KA</sub> = 10 mA			14	34	mV
	Ratio of change in			$\Delta V_{KA} = 10 \text{ V} - V_{ref}$		-1.4	-2.7	mV/V
ΔV <sub>ref</sub> / ΔV <sub>KA</sub>	reference voltage to the change in cathode voltage	See Figure 8-2	I <sub>KA</sub> = 10 mA	ΔV <sub>KA</sub> = 36 V - 10 V		-1	-2	mV/V
I <sub>ref</sub>	Reference Input Current	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		2	4	μA
I <sub>I(dev)</sub>	Deviation of reference input current over full temperature range (1)	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		0.8	2.5	μА
I <sub>min</sub>	Minimum cathode current for regulation	See Figure 8-1	V <sub>KA</sub> = V <sub>ref</sub>			0.4	0.7	mA
I <sub>off</sub>	Off-state cathode current	See Figure 8-3	V <sub>KA</sub> = 36 V, V <sub>ref</sub> = 0			0.1	0.5	μA
Z <sub>KA</sub>	Dynamic Impedance (2)	See Figure 8-1	$V_{KA} = V_{ref}, f \le 1 \text{ kHz},$ $I_{KA} = 1 \text{ mA to } 100 \text{ mA}$			0.2	0.5	Ω

<sup>(1)</sup> The deviation parameters V<sub>I(dev)</sub> and I<sub>I(dev)</sub> are defined as the differences between the maximum and minimum values obtained over the rated temperature range. For more details on V<sub>I(dev)</sub> and how it relates to the average temperature coefficient, see Temperature Coefficient.

<sup>(2)</sup> The dynamic impedance is defined by  $|Z_{KA}| = \Delta V_{KA}/\Delta I_{KA}$ . For more details on  $|Z_{KA}|$  and how it relates to  $V_{KA}$ , see Dynamic Impedance.



## 7.13 Electrical Characteristics, TL431BQ, TL432BQ

over recommended operating conditions, T<sub>A</sub> = 25°C (unless otherwise noted)

	PARAMETER	TEST CIRCUIT	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
V <sub>ref</sub>	Reference Voltage	See Figure 8-1	$V_{KA} = V_{ref}$ , $I_{KA} = 10 \text{ mA}$		2483	2495	2507	mV
V <sub>I(dev)</sub>	Deviation of reference input voltage over full temperature range (1)	See Figure 8-1	V <sub>KA</sub> = V <sub>ref</sub> , I <sub>KA</sub> = 10 mA			14	34	mV
	Ratio of change in			$\Delta V_{KA} = 10 \text{ V} - V_{ref}$		-1.4	-2.7	mV/V
$\Delta V_{ref}$ / $\Delta V_{KA}$	reference voltage to the change in cathode voltage	See Figure 8-2	I <sub>KA</sub> = 10 mA	ΔV <sub>KA</sub> = 36 V - 10 V		-1	-2	mV/V
I <sub>ref</sub>	Reference Input Current	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		2	4	μΑ
I <sub>I(dev)</sub>	Deviation of reference input current over full temperature range (1)	See Figure 8-2	$I_{KA} = 10 \text{ mA}, R1 = 10 \text{k}\Omega,$	R2 = ∞		0.8	2.5	μА
I <sub>min</sub>	Minimum cathode current for regulation	See Figure 8-1	V <sub>KA</sub> = V <sub>ref</sub>			0.4	0.7	mA
I <sub>off</sub>	Off-state cathode current	See Figure 8-3	V <sub>KA</sub> = 36 V, V <sub>ref</sub> = 0			0.1	0.5	μΑ
Z <sub>KA</sub>	Dynamic Impedance (2)	See Figure 8-1	$V_{KA} = V_{ref}, f \le 1 \text{ kHz},$ $I_{KA} = 1 \text{ mA to } 100 \text{ mA}$			0.2	0.5	Ω

The deviation parameters  $V_{l(dev)}$  and  $I_{l(dev)}$  are defined as the differences between the maximum and minimum values obtained over the rated temperature range. For more details on  $V_{l(dev)}$  and how it relates to the average temperature coefficient, see Temperature

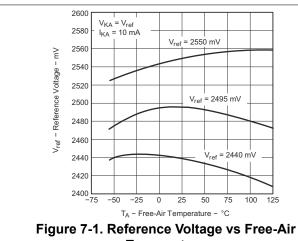
Product Folder Links: TL431 TL432

<sup>(2)</sup> The dynamic impedance is defined by  $|Z_{KA}| = \Delta V_{KA}/\Delta I_{KA}$ . For more details on  $|Z_{KA}|$  and how it relates to  $V_{KA}$ , see Dynamic



### 7.14 Typical Characteristics

Data at high and low temperatures are applicable only within the recommended operating free-air temperature ranges of the various devices.



**Temperature** 

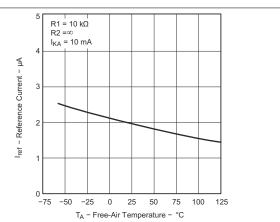


Figure 7-2. Reference Current vs Free-Air **Temperature** 

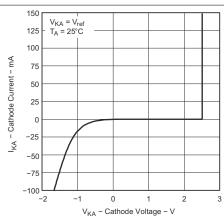


Figure 7-3. Cathode Current vs Cathode Voltage

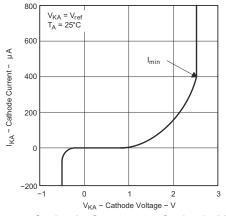


Figure 7-4. Cathode Current vs Cathode Voltage

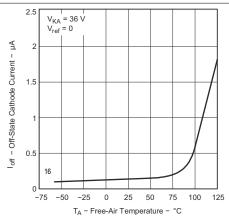


Figure 7-5. Off-State Cathode Current vs Free-Air **Temperature** 

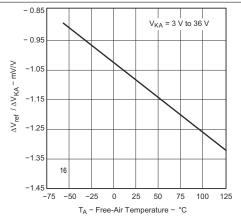
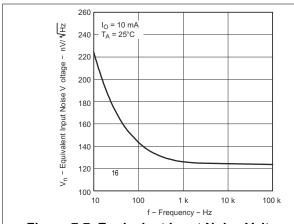


Figure 7-6. Ratio of Delta Reference Voltage to **Delta Cathode Voltage vs Free-Air Temperature** 





0 1 2 3 4 5 6 7 8 9 10 t - Time - s

Figure 7-7. Equivalent Input Noise Voltage vs Frequency

Figure 7-8. Equivalent Input Noise Voltage Over a 10-S Period

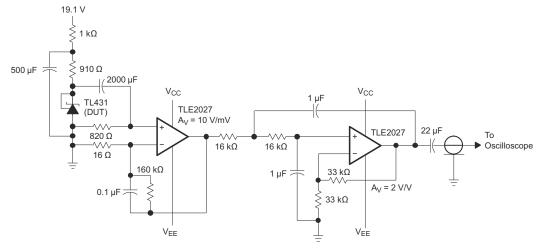
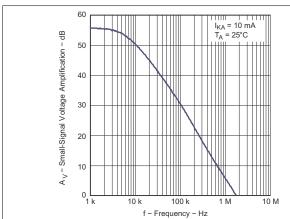
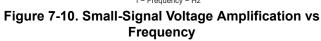


Figure 7-9. Test Circuit for Equivalent Input Noise Voltage Over a 10-S Period





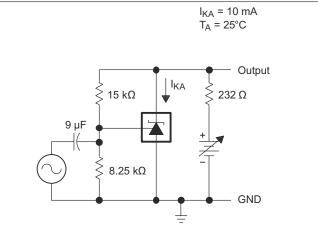


Figure 7-11. Test Circuit for Voltage Amplification

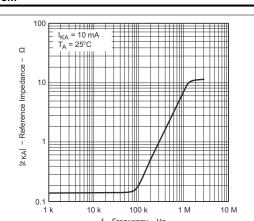


Figure 7-12. Reference Impedance vs Frequency

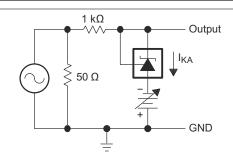


Figure 7-13. Test Circuit for Reference Impedance

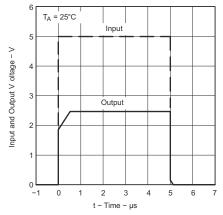


Figure 7-14. Pulse Response

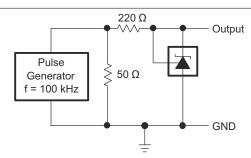
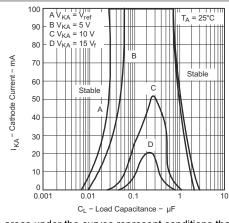
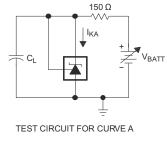


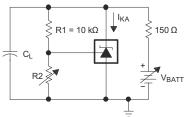
Figure 7-15. Test Circuit for Pulse Response



The areas under the curves represent conditions that may cause the device to oscillate. For curves B, C, and D, R2 and V+ are adjusted to establish the initial  $V_{KA}$  and  $I_{KA}$  conditions, with  $C_L$  = 0. VBATT and  $C_L$  then are adjusted to determine the ranges of stability.

Figure 7-16. Stability Boundary Conditions for All TL431 and TL431A Devices (Except for SOT23-3, SC-70, and Q-Temp Devices)

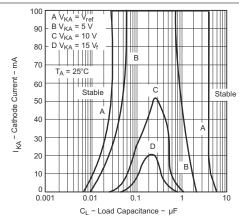




TEST CIRCUIT FOR CURVES B, C, AND D

Figure 7-17. Test Circuits for Stability Boundary Conditions





The areas under the curves represent conditions that may cause the device to oscillate. For curves B, C, and D, R2 and V+ are adjusted to establish the initial  $V_{KA}$  and  $I_{KA}$  conditions, with  $C_L$  = 0. VBATT and  $C_L$  then are adjusted to determine the ranges of stability.

Figure 7-18. Stability Boundary Conditions for All TL431B, TL432, SOT-23, SC-70, and Q-Temp Devices

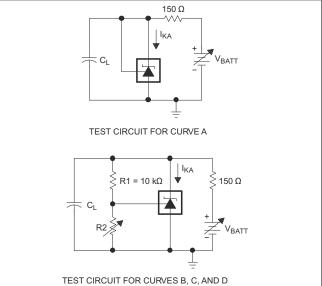


Figure 7-19. Test Circuit for Stability Boundary Conditions

#### **8 Parameter Measurement Information**

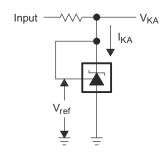


Figure 8-1. Test Circuit for  $V_{KA} = V_{ref}$ 

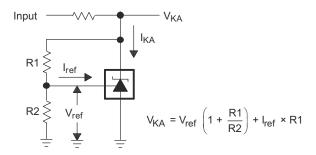


Figure 8-2. Test Circuit for  $V_{KA} > V_{ref}$ 

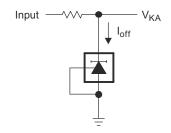


Figure 8-3. Test Circuit for Ioff

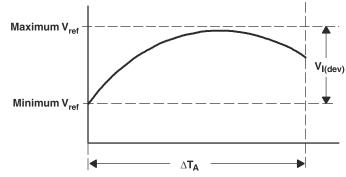
### 8.1 Temperature Coefficient

The deviation of the reference voltage,  $V_{ref}$ , over the full temperature range is known as  $V_{I(dev)}$ . The parameter of  $V_{I(dev)}$  can be used to find the temperature coefficient of the device. The average full-range temperature coefficient of the reference input voltage,  $\alpha_{Vref}$ , is defined as:

$$\left| \alpha_{\text{vref}} \right| \left( \frac{\text{ppm}}{^{\circ}\text{C}} \right) = \frac{\left( \frac{\text{V}_{\text{I(dev)}}}{\text{V}_{\text{ref}} \text{ at } 25^{\circ}\text{C}} \right) \times 10^{6}}{\Delta T_{\text{A}}}$$

where:

 $\Delta T_{\mbox{\scriptsize A}}$  is the rated operating temperature range of the device.



 $\alpha_{Vref}$  is positive or negative, depending on whether minimum  $V_{ref}$  or maximum  $V_{ref}$ , respectively, occurs at the lower temperature. The full-range temperature coefficient is an average and therefore any subsection of the rated operating temperature range can yield a value that is greater or less than the average. For more details on temperature coefficient, refer to the *Voltage Reference Selection Basics White Paper*.

Copyright © 2023 Texas Instruments Incorporated

Submit Document Feedback



## 8.2 Dynamic Impedance

The dynamic impedance is defined as  $|Z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_{KA}}$ . When the device is operating with two external resistors

(see Figure 7-13), the total dynamic impedance of the circuit is given by  $|z'| = \frac{\Delta V}{\Delta I}$ , which is approximately equal to  $|Z_{KA}| \left(1 + \frac{R1}{R2}\right)$ 

The  $V_{KA}$  of the device can be affected by the dynamic impedance. The device test current  $I_{test}$  for  $V_{KA}$  is specified in the *Electrical Characteristics*. Any deviation from  $I_{test}$  can cause deviation on the output  $V_{KA}$ . Figure 8-4 shows the effect of the dynamic impedance on the  $V_{KA}$ .

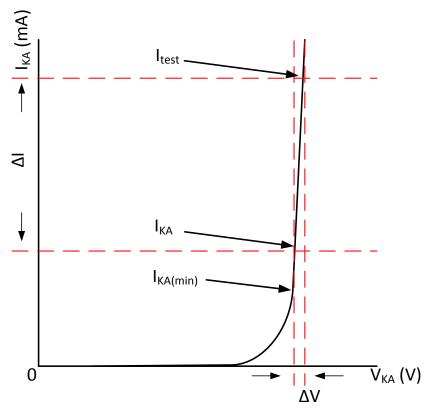


Figure 8-4. Dynamic Impedance

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

## 9 Detailed Description

#### 9.1 Overview

This standard device has proven ubiquity and versatility across a wide range of applications, ranging from power to signal path. This is due to its key components containing an accurate voltage reference & opamp, which are very fundamental analog building blocks. TL43xx is used in conjunction with its key components to behave as a single voltage reference, error amplifier, voltage clamp or comparator with integrated reference.

TL43xx can be operated and adjusted to cathode voltages from 2.5V to 36V, making this part optimum for a wide range of end equipments in industrial, auto, telecom & computing. In order for this device to behave as a shunt regulator or error amplifier, >1mA (I<sub>min</sub>(max)) must be supplied in to the cathode pin. Under this condition, feedback can be applied from the Cathode and Ref pins to create a replica of the internal reference voltage.

Various reference voltage options can be purchased with initial tolerances (at 25°C) of 0.5%, 1%, and 2%. These reference options are denoted by B (0.5%), A (1.0%) and blank (2.0%) after the TL431 or TL432. TL431 & TL432 are both functionally, but have separate pinout options.

The TL43xxC devices are characterized for operation from 0°C to 70°C, the TL43xxI devices are characterized for operation from -40°C to 85°C, and the TL43xxQ devices are characterized for operation from -40°C to 125°C.

## 9.2 Functional Block Diagram

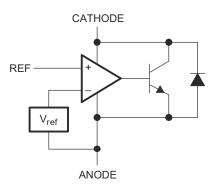


Figure 9-1. Equivalent Schematic

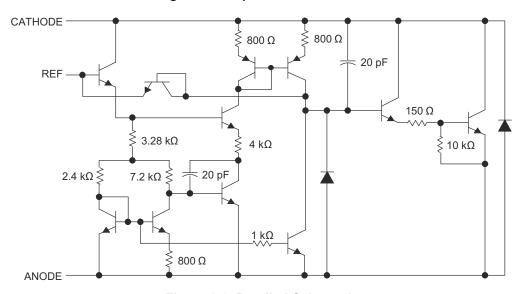


Figure 9-2. Detailed Schematic



#### 9.3 Feature Description

TL43xx consists of an internal reference and amplifier that outputs a sink current base on the difference between the reference pin and the virtual internal pin. The sink current is produced by the internal Darlington pair, shown in the above schematic (Figure 9-2). A Darlington pair is used in order for this device to be able to sink a maximum current of 100 mA.

When operated with enough voltage headroom ( $\geq 2.5$  V) and cathode current ( $I_{KA}$ ), TL431 forces the reference pin to 2.5 V. However, the reference pin can not be left floating, as it needs  $I_{REF} \geq 4 \,\mu\text{A}$  (please see *Electrical Characteristics*, *TL431C*, *TL432C*). This is because the reference pin is driven into an npn, which needs base current in order operate properly.

When feedback is applied from the Cathode and Reference pins, TL43xx behaves as a Zener diode, regulating to a constant voltage dependent on current being supplied into the cathode. This is due to the internal amplifier and reference entering the proper operating regions. The same amount of current needed in the above feedback situation must be applied to this device in open loop, servo or error amplifying implementations in order for it to be in the proper linear region giving TL43xx enough gain.

Unlike many linear regulators, TL43xx is internally compensated to be stable without an output capacitor between the cathode and anode. However, if it is desired to use an output capacitor Figure 7-18 can be used as a guide to assist in choosing the correct capacitor to maintain stability.

#### 9.4 Device Functional Modes

#### 9.4.1 Open Loop (Comparator)

When the cathode/output voltage or current of TL43xx is not being fed back to the reference/input pin in any form, this device is operating in open loop. With proper cathode current (Ika) applied to this device, TL43xx will have the characteristics shown in Figure 10-2. With such high gain in this configuration, TL43xx is typically used as a comparator. With the reference integrated makes TL43xx the prefered choice when users are trying to monitor a certain level of a single signal.

#### 9.4.2 Closed Loop

When the cathode/output voltage or current of TL43xx is being fed back to the reference/input pin in any form, this device is operating in closed loop. The majority of applications involving TL43xx use it in this manner to regulate a fixed voltage or current. The feedback enables this device to behave as an error amplifier, computing a portion of the output voltage and adjusting it to maintain the desired regulation. This is done by relating the output voltage back to the reference pin in a manner to make it equal to the internal reference voltage, which can be accomplished via resistive or direct feedback.

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

## 10 Applications and Implementation

#### **Note**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

## 10.1 Application Information

As this device has many applications and setups, there are many situations that this datasheet can not characterize in detail. The linked application notes will help the designer make the best choices when using this part.

Application note *Understanding Stability Boundary Conditions Charts in TL431, TL432 Data Sheet* (SLVA482) will provide a deeper understanding of this devices stability characteristics and aid the user in making the right choices when choosing a load capacitor. Application note *Setting the Shunt Voltage on an Adjustable Shunt Regulator* (SLVA445) assists designers in setting the shunt voltage to achieve optimum accuracy for this device.

## 10.2 Typical Applications

#### 10.2.1 Comparator With Integrated Reference

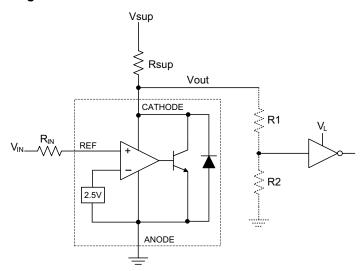


Figure 10-1. Comparator Application Schematic



#### 10.2.1.1 Design Requirements

For this design example, use the parameters listed in *Table 10-1* as the input parameters.

Table 10-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input Voltage Range	0 V to 5 V
Input Resistance	10 kΩ
Supply Voltage	24 V
Cathode Current (lk)	5 mA
Output Voltage Level	~2 V – V <sub>SUP</sub>
Logic Input Thresholds VIH/VIL	V <sub>L</sub>

#### 10.2.1.2 Detailed Design Procedure

When using TL431 as a comparator with reference, determine the following:

- Input Voltage Range
- Reference Voltage Accuracy
- · Output logic input high and low level thresholds
- Current Source resistance

#### 10.2.1.2.1 Basic Operation

In the configuration shown in Figure 10-1 TL431 will behave as a comparator, comparing the  $V_{REF}$  pin voltage to the internal virtual reference voltage. When provided a proper cathode current ( $I_K$ ), TL43xx will have enough open loop gain to provide a quick response. This can be seen in Figure 10-2, where the  $R_{SUP}$ =10 k $\Omega$  ( $I_{KA}$ =500  $\mu$ A) situation responds much slower than  $R_{SUP}$ =1 k $\Omega$  ( $I_{KA}$ =5 mA). Operation near and below  $I_{min}$  could result in low gain, leading to a slow response.

#### 10.2.1.2.1.1 Overdrive

Slow or inaccurate responses can also occur when the reference pin is not provided enough overdrive voltage. This is the amount of voltage that is higher than the internal virtual reference. The internal virtual reference voltage will be within the range of  $2.5 \text{ V} \pm (0.5\%, 1.0\% \text{ or } 1.5\%)$  depending on which version is being used. The more overdrive voltage provided, the faster the TL431 will respond.

For applications where TL431 is being used as a comparator, it is best to set the trip point to greater than the positive expected error (i.e.  $\pm 1.0\%$  for the A version). For fast response, setting the trip point to  $\pm 1.0\%$  of the internal  $\pm 1.0\%$  internal  $\pm 1.0\%$  for the A version).

For minimal voltage drop or difference from Vin to the ref pin, it is recommended to use an input resistor  $<10k\Omega$  to provide Iref.

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

#### 10.2.1.2.2 Output Voltage and Logic Input Level

In order for TL431 to properly be used as a comparator, the logic output must be readable by the receiving logic device. This is accomplished by knowing the input high and low level threshold voltage levels, typically denoted by  $V_{IH}$  &  $V_{IL}$ .

As seen in Figure 10-2, TL431's output low level voltage in open-loop/comparator mode is ~2 V, which is typically sufficient for 5V supplied logic. However, would not work for 3.3 V & 1.8 V supplied logic. In order to accomodate this a resistive divider can be tied to the output to attenuate the output voltage to a voltage legible to the receiving low voltage logic device.

TL431's output high voltage is equal to  $V_{SUP}$  due to TL431 being open-collector. If  $V_{SUP}$  is much higher than the receiving logic's maximum input voltage tolerance, the output must be attenuated to accomadate the outgoing logic's reliability.

When using a resistive divider on the output, be sure to make the sum of the resistive divider (R1 & R2 in Figure 10-1) is much greater than  $R_{SUP}$  in order to not interfere with TL431's ability to pull close to  $V_{SUP}$  when turning off.

#### 10.2.1.2.2.1 Input Resistance

TL431 requires an input resistance in this application in order to source the reference current ( $I_{REF}$ ) needed from this device to be in the proper operating regions while turing on. The actual voltage seen at the ref pin will be  $V_{REF}=V_{IN}-I_{REF}*R_{IN}$ . Since  $I_{REF}$  can be as high as 4  $\mu$ A it is recommended to use a resistance small enough that will mitigate the error that  $I_{REF}$  creates from  $V_{IN}$ .

#### 10.2.1.3 Application Curve

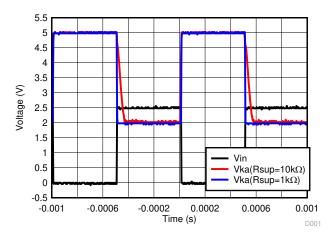


Figure 10-2. Output Response With Various Cathode Currents



#### 10.2.2 Shunt Regulator/Reference

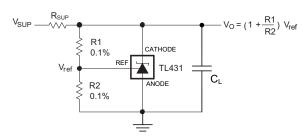


Figure 10-3. Shunt Regulator Schematic

## 10.2.2.1 Design Requirements

For this design example, use the parameters listed in Table 10-1 as the input parameters.

EXAMPLE VALUE
LAMIFIE VALUE
1.0 %
24 V
5 mA
2.5 V - 36 V
10 μF
10 kΩ

Table 10-2. Design Parameters

### 10.2.2.2 Detailed Design Procedure

When using TL431 as a Shunt Regulator, determine the following:

- · Input Voltage Range
- Temperature Range
- Total Accuracy
- Cathode Current
- Reference Initial Accuracy
- Output Capacitance

#### 10.2.2.2.1 Programming Output/Cathode Voltage

In order to program the cathode voltage to a regulated voltage a resistive bridge must be shunted between the cathode and anode pins with the mid point tied to the reference pin. This can be seen in Figure 10-3, with R1 & R2 being the resistive bridge. The cathode/output voltage in the shunt regulator configuration can be approximated by the equation shown in Figure 10-3. The cathode voltage can be more accurated determined by taking in to account the cathode current:

In order for this equation to be valid, TL43xx must be fully biased so that it has enough open loop gain to mitigate any gain error. This can be done by meeting the Imin spec denoted in *Electrical Characteristics*, *TL431C*, *TL432C*.

Product Folder Links: TL431 TL432

ubmit Document Feedback

#### 10.2.2.2.2 Total Accuracy

When programming the output above unity gain ( $V_{KA}=V_{REF}$ ), TL43xx is susceptible to other errors that may effect the overall accuracy beyond  $V_{REF}$ . These errors include:

- · R1 and R2 accuracies
- V<sub>I(dev)</sub> Change in reference voltage over temperature
- $\Delta V_{REF} / \Delta V_{KA}$  Change in reference voltage to the change in cathode voltage
- |z<sub>KA</sub>| Dynamic impedance, causing a change in cathode voltage with cathode current

Worst case cathode voltage can be determined taking all of the variables in to account. Application note *Setting the Shunt Voltage on an Adjustable Shunt Regulator* (SLVA445) assists designers in setting the shunt voltage to achieve optimum accuracy for this device.

#### 10.2.2.2.3 Stability

Though TL43xx is stable with no capacitive load, the device that receives the shunt regulator's output voltage could present a capacitive load that is within the TL43xx region of stability, shown in Figure 7-16 and Figure 7-18. Also, designers may use capacitive loads to improve the transient response or for power supply decoupling. When using additional capacitance between Cathode and Anode, refer to Figure 7-16 and Figure 7-18. Also, application note *Understanding Stability Boundary Conditions Charts in TL431, TL432 Data Sheet* (SLVA482) will provide a deeper understanding of this devices stability characteristics and aid the user in making the right choices when choosing a load capacitor.

#### 10.2.2.2.4 Start-Up Time

As shown in Figure 10-4, TL43xx has a fast response up to ~2 V and then slowly charges to its programmed value. This is due to the compensation capacitance (shown in Figure 7-18) the TL43xx has to meet its stability criteria. Despite the secondary delay, TL43xx still has a fast response suitable for many clamp applications.

## 10.2.2.3 Application Curve

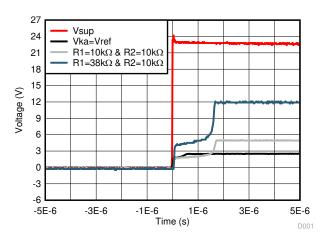
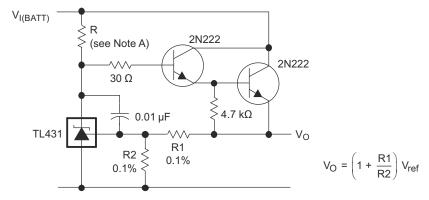


Figure 10-4. TL43xx Start-Up Response



#### 10.3 System Examples



A. R should provide cathode current ≥1 mA to the TL431 at minimum V<sub>(BATT)</sub>.

Figure 10-5. Precision High-Current Series Regulator

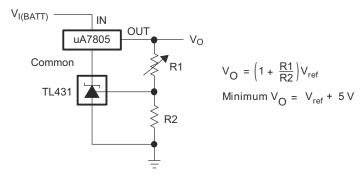


Figure 10-6. Output Control of a Three-Terminal Fixed Regulator

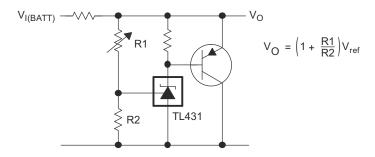
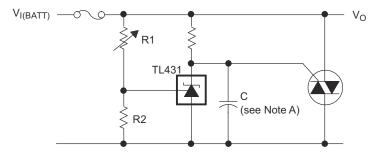


Figure 10-7. High-Current Shunt Regulator



A. Refer to the stability boundary conditions in Figure 7-16 and Figure 7-18 to determine allowable values for C.

Figure 10-8. Crowbar Circuit

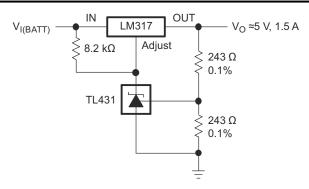
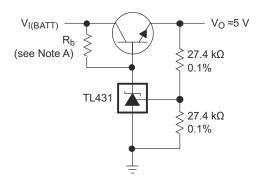


Figure 10-9. Precision 5-V, 1.5-A Regulator



A. R<sub>b</sub> should provide cathode current ≥1 mA to the TL431.

Figure 10-10. Efficient 5-V Precision Regulator

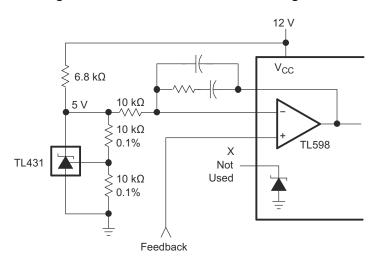
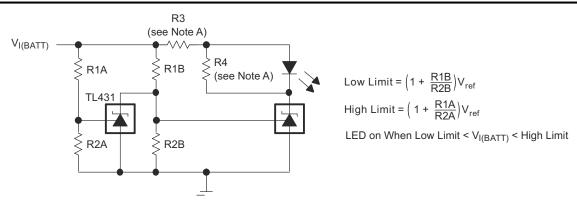


Figure 10-11. PWM Converter With Reference





A. Select R3 and R4 to provide the desired LED intensity and cathode current ≥1 mA to the TL431 at the available V<sub>I(BATT)</sub>.

## Figure 10-12. Voltage Monitor

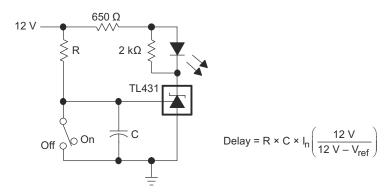


Figure 10-13. Delay Timer

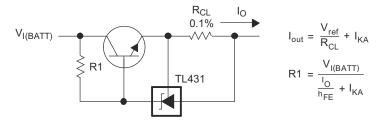


Figure 10-14. Precision Current Limiter

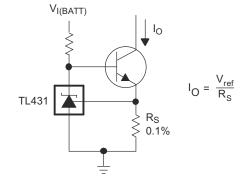


Figure 10-15. Precision Constant-Current Sink

Submit Document Feedback

### 10.4 Power Supply Recommendations

When using TL43xx as a Linear Regulator to supply a load, designers will typically use a bypass capacitor on the output/cathode pin. When doing this, be sure that the capacitance is within the stability criteria shown in Figure 7-16 and Figure 7-18.

In order to not exceed the maximum cathode current, be sure that the supply voltage is current limited. Also, be sure to limit the current being driven into the Ref pin, as not to exceed its absolute maximum rating.

For applications shunting high currents, pay attention to the cathode and anode trace lengths, adjusting the width of the traces to have the proper current density.

#### 10.5 Layout

### 10.5.1 Layout Guidelines

Bypass capacitors should be placed as close to the part as possible. Current-carrying traces need to have widths appropriate for the amount of current they are carrying; in the case of the TL43xx, these currents will be low.

#### 10.5.2 Layout Example

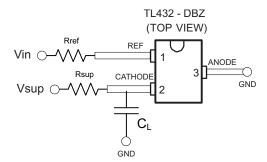


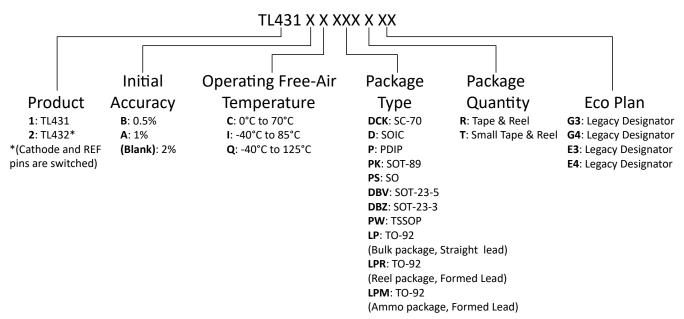
Figure 10-16. DBZ Layout Example



## 11 Device and Documentation Support

#### 11.1 Device Nomenclature

TI assigns suffixes and prefixes to differentiate all the combinations of the TL43x family. The Eco Plan designator is a legacy designator that was used to differentiate Pb-free and Green devices. More details and possible orderable combinations are located on the Package Option Addendum in Mechanical, Packaging, and Orderable Information.



#### 11.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

TECHNICAL **TOOLS & SUPPORT &** PRODUCT FOLDER **PARTS** SAMPLE & BUY **DOCUMENTS** SOFTWARE COMMUNITY TL431 Click here Click here Click here Click here Click here TL432 Click here Click here Click here Click here Click here

Table 11-1. Related Links

## 11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 11.4 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 11.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

## 11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 11.7 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

Copyright © 2023 Texas Instruments Incorporated

Submit Document Feedback

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023, Texas Instruments Incorporated